

Description

The F1958 is part of IDT's *Glitch-Free*TM family of DSAs optimized for the demanding requirements of Base Station (BTS) radio cards and numerous other applications. This device is offered in a compact 4mm x 4mm 24-pin package with 50Ω input and output impedance for ease of integration into the radio or RF system.

The F1958 offers very high reliability due to its construction from a monolithic silicon die in a QFN package. The insertion loss is very low with minimal distortion. Additionally, the device is designed to have extremely accurate attenuation levels. These accurate attenuation levels improve system SNR and/or ACLR by ensuring system gain is as close to the targeted level as possible. In addition, the very fast settling time in parallel mode is ideal for fast switching systems. Finally, the device uses our *Glitch-Free*TM technology in contrast to competing DSAs.

Competitive Advantage

- Lowest insertion loss for best SNR
- Glitch-Free™ technology to protect power amplifiers or ADC during transitions between attenuation states
- Extremely accurate attenuation levels
- Ultra-low distortion
- MSL1 and 2000 V HBM ESD

Typical Applications

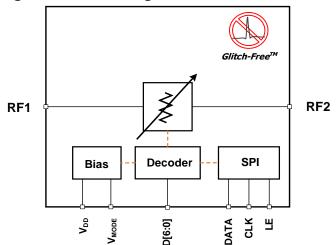
- 3G/4G/4G+ Base Station Systems
- Distributed Antenna Systems, DAS
- Remote Radio Heads
- Active Antenna Systems, AAS Broadband Satellite Equipment
- NFC Infrastructure
- Military Communication Equipment

Features

- Serial and 7-bit parallel interface
- 31.75dB range
- 0.25dB steps
- Glitch-FreeTM: low transient overshoot
- 500ns settling time for 0.25dB steps
- Ultra linear > 63dBm IIP3
- Low insertion loss < 1.7dB at 4GHz
- Attenuation error < ±0.2dB at 4GHz
- Bi-directional RF use
- 3.3V or 5V supply
- -40°C to +105°C operating temperature
- 4mm x 4mm Thin QFN 24-pin package

Block Diagram

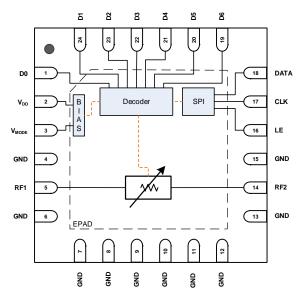
Figure 1. Block Diagram





Pin Assignments

Figure 2. Pin Assignments for 4mm x 4mm x 0.75mm TQFN Package – Top View



Pin Descriptions

Table 1. Pin Descriptions

Number	Name	Description
1	D0	Parallel control pin – 0.25dB. Pull high for attenuation.
2	V_{DD}	Power supply input. Bypass to ground with capacitors as close as possible to pin.
3	V_{MODE}	Parallel or serial programming mode pin. Leave open or logic LOW for parallel mode. Logic HIGH for serial mode.
4, 6 - 13, 15	GND	Internally grounded. These pins must be grounded as close to the device as possible.
5	RF1	RF Port 1. Can be used as either the input or output RF (bi-directional). Port must be at 0V DC. An external AC coupling capacitor must be used if there is a DC voltage present.
14	RF2	RF Port 2. Can be used as either the input or output RF (bi-directional). Port must be at 0V DC. An external AC coupling capacitor must be used if there is a DC voltage present.
16	LE	Serial latch enable.
17	CLK	Serial clock input.
18	DATA	Serial data input.
19	D6	Parallel control pin – 16dB. Pull HIGH for attenuation. [a]
20	D5	Parallel control pin – 8dB. Pull HIGH for attenuation. [a]
21	D4	Parallel control pin – 4dB. Pull HIGH for attenuation. [a]
22	D3	Parallel control pin – 2dB. Pull HIGH for attenuation. [a]
23	D2	Parallel control pin – 1dB. Pull HIGH for attenuation. [a]
24	D1	Parallel control pin – 0.5dB. Pull HIGH for attenuation. [a]
	– EPAD	Exposed paddle. Internally connected to ground. Solder this exposed paddle to a printed circuit board (PCB) pad that uses multiple ground vias to provide heat transfer out of the device into the PCB ground planes. These multiple ground vias are also required to achieve the specified RF performance.

[[]a] There is a $500k\Omega$ pull-down resistor to ground.



Absolute Maximum Ratings

The absolute maximum ratings are stress ratings only. Stresses greater than those listed below can cause permanent damage to the device. Functional operation of the F1958 at absolute maximum ratings is not implied. Exposure to absolute maximum rating conditions may affect device reliability.

Table 2. Absolute Maximum Ratings

Parameter	Symbol	Minimum	Maximum	Units
Power Supply Voltage	V_{DD}	-0.3	5.8	V
V _{MODE} , DATA, CLK, LE, D[6:0]	V_{CTRL}	-0.3	Lower of (V _{DD} +0.25, 5.8)	V
RF1, RF2	V_{RF}	-0.3	0.3	V
Maximum RF Input Power to RF1 or RF2 (> 100 MHz)	P_{MAX}		+34	dBm
Junction Temperature	T_{JMAX}		+150	°C
Storage Temperature Range	T _{STOR}	-65	+150	°C
Lead Temperature (soldering, 10s)	T_{LEAD}		+260	°C
Electrostatic Discharge – HBM (JEDEC/ESDA JS-001-2012)	V _{ESDHMB}		2000 (Class 2)	V
Electrostatic Discharge – CDM (JEDEC 22-C101F)	V _{ESDCDM}		1000 (Class C3)	V

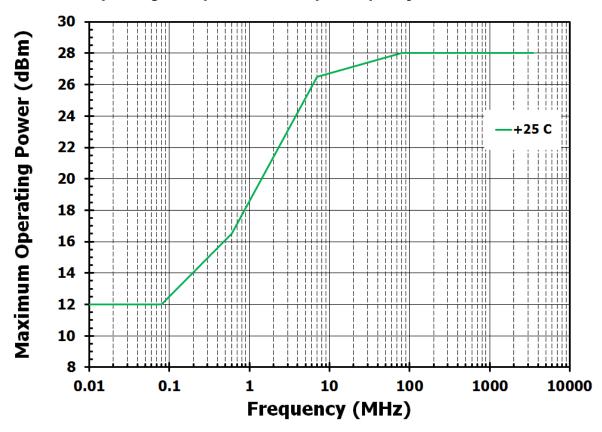


Recommended Operating Conditions

Table 3. Recommended Operating Conditions

Parameter	Symbol	Condition	Minimum	Typical	Maximum	Units
Power Supply Voltage	V_{DD}		3.0		5.5	V
Operating Temperature Range	T _{EP}	Exposed paddle	-40		+105	°C
RF Frequency Range	f_{RF}		0.001		6	GHz
Maximum Input Power	P _{MAX}	RF1 or RF2			See Figure 3	dBm
RF Peak Input Power	Рреак	RF1 Port, V _{DD} = 3.3V, T _{EP} = 85°C, f _{RF} > 500MHz, WCDMA, 3GPP, Downlink, 64 DPCH, Chip rate = 3.84MSPS, Avg. P _{IN} = +22dBm 1 % 0.1 % 0.01 % 0.001 %			28.9 30.7 32.3 33.2	dBm
RF1 Port Impedance	Z ₁			50		Ω
RF2 Port Impedance	Z ₂			50		Ω

Figure 3. Maximum Operating CW Input Power vs. Input Frequency





Electrical Characteristics

Table 4. Electrical Characteristics

Specifications apply at V_{DD} = 3.3V, T_{EP} = 25°C, f_{RF} = 2GHz, LSB = 0.25dB steps and Evaluation Board (EVKit) trace and connector losses are de-embedded, unless otherwise noted. Minimum attenuation D[6:0] = [0000000], Maximum attenuation D[6:0] = [11111111].

Parameter	Symbol	Condition	Minimum	Typical	Maximum	Units
Logic Input HIGH	V _{IH}	All logic pins	2.6 ^[a]		5.5	V
Logic Input LOW	V _{IL}	All logic pins	0		1	V
Logic Current	I _{IH} , I _{IL}		-15		+15	μA
DC Command		V _{DD} = 3.3V		250	400	
DC Current	I _{DD}	V _{DD} = 5.5V		310		μA
Attenuation Range		No missing codes		31.75		dB
		f _{RF} < 4.0GHz		0.25		
Minimum Gain Step for Monotonicity	LSB	f _{RF} < 6.0GHz		0.50		dB
		f _{RF} < 8.0GHz		1.00		
DOA O W. T. M.		Max to min attenuation to settle to within 0.5dB of final value		1.2		
DSA Settling Time [b]	t _{SET}	Min to max attenuation to settle to within 0.5dB of final value		2.0		- μs
Maximum Video Feed-Through	VID _{FT}	Measured with 10ns rise time, 0V to 3.3V control pulse		10		mV_{pp}
Maximum Spurious Level on any RF Port ^[G]	SPUR _{MAX}	Unused RF ports terminated into 50Ω		-118		dBm
Serial Clock Speed	f _{CLK}				10	MHz
Parallel to Serial Setup	t _{PS}		100			ns
Serial Data Hold Time	t _H		10			ns
LE Delay		Time from final serial clock rising edge	10			ns
Maximum Switch Rate	SW _{RATE}			25		kHz

[[]a] Specifications in the minimum/maximum columns that are shown in **bold italics** are guaranteed by test. Specifications in these columns that are not shown in bold italics are guaranteed by design characterization.

[[]b] Speeds are measured after SPI programming is completed (data latched with LE = LOW to HIGH transition).

[[]c] Spurious due to on-chip negative voltage generator. Typical generator fundamental frequency is 2.2MHz.



Electrical Characteristics

Table 5. Electrical Characteristics

Specifications apply at V_{DD} = 3.3V, T_{EP} = 25°C, f_{RF} = 2GHz, LSB = 0.25dB steps and Evaluation Board (EVKit) trace and connector losses are de-embedded, unless otherwise noted. Minimum attenuation D[6:0] = [0000000], Maximum attenuation D[6:0] = [11111111].

Parameter	Symbol	Condition	Minimum	Typical	Maximum	Units	
		$1MHz \le f_{RF} \le 1GHz$		1.1			
		1GHz < f _{RF} ≤ 2GHz		1.3	1.8 ^[a]		
Insertion Loss	IL	2GHz < f _{RF} ≤ 3GHz		1.5		dB	
IIISEI (IOIT LOSS	IL	3GHz < f _{RF} ≤ 4GHz		1.6		ub l	
		4GHz < f _{RF} ≤ 5GHz		1.9			
		5GHz < f _{RF} ≤ 6GHz		2.6			
		f _{RF} = 1GHz		12			
Relative Phase Between the	ф	f _{RF} = 2GHz		25		doa	
Minimum and Maximum Attenuation	Φ_{Δ}	f _{RF} = 4GHz		50		deg -	
		f _{RF} = 6GHz		70			
Step Error	DNL	Maximum error between any two adjacent attenuation levels		0.15	0.28	dB	
Absolute Attenuation Force	INL	Max. error for state 19.75dB, f _{RF} = 2000MHz	-0.4		+0.5	٩D	
Absolute Attenuation Error	IINL	Max. error, over all states f _{RF} = 2000MHz	-0.8	-0.25 +0.08	+0.5	- dB	
		$1MHz \le f_{RF} \le 2GHz$		20			
RF1 Port Return Loss	RL_1	2GHz < f _{RF} ≤ 4GHz		17		dB	
		4GHz < f _{RF} ≤ 6GHz		13			
		$1MHz \le f_{RF} \le 2GHz$		20			
RF2 Port Return Loss	RL_2	2GHz < f _{RF} ≤ 4GHz		16 dB		dB	
		4GHz < f _{RF} ≤ 6GHz		12			

[[]a] Specifications in the minimum/maximum columns that are shown in **bold italics** are guaranteed by test. Specifications in these columns that are not shown in bold italics are guaranteed by design characterization.



Electrical Characteristics

Table 6. Electrical Characteristics

Specifications apply at V_{DD} = 3.3V, T_{EP} = 25°C, f_{RF} = 2GHz, LSB = 0.25dB steps and Evaluation Board (EVKit) trace and connector losses are de-embedded, unless otherwise noted. Minimum attenuation D[6:0] = [0000000], Maximum attenuation D[6:0] = [11111111].

Parameter	Symbol	Condition	Minimum	Typical	Maximum	Units	
		P _{IN} = +19dBm per tone 50MHz tone separation					
		Attn = 0.00dB		64			
		Attn = 15.75dB		64		dBm	
	IIP3	Attn = 31.75dB		64			
Input IP3		P _{IN} = +16dBm per tone 1MHz tone separation					
		f _{RF} = 0.7GHz	60 [a]	63.3			
		f _{RF} = 1.8GHz	60	63.7		dD.m	
		f _{RF} = 2.2GHz	60	63.4		dBm	
		f _{RF} = 2.6GHz	60	63.7			
Input 0.1dB Compression [b]	IP _{0.1dB}			35		dBm	

[[]a] Specifications in the minimum/maximum columns that are shown in **bold italics** are guaranteed by test. Specifications in these columns that are not shown in bold italics are guaranteed by design characterization.

[[]b] The input 0.1dB compression point is a linearity figure of merit. Refer to the Recommended Operating Conditions section and Figure 3 for the maximum operating power levels.



Thermal Characteristics

Table 7. Package Thermal Characteristics

Parameter	Symbol	Value	Units
Junction to Ambient Thermal Resistance	θ_{JA}	42	°C/W
Junction to Case Thermal Resistance (case is defined as the exposed paddle)	ӨЈС-ВОТ	8	°C/W
Moisture Sensitivity Rating (Per J-STD-020)		MSL 1	

Typical Operating Conditions (TOC)

- V_{DD} = 3.3V
- $Z_L = Z_S = 50\Omega$
- T_{EP} = 25°C
- f_{RF} = 2.0GHz
- Attenuation setting = 0 dB = D[6:0] =[0000000]
- P_{in} = +16dBm / tone
- 50MHz tone spacing
- All temperatures are referenced to the exposed paddle
- Evaluation Kit traces and connector losses are de-embedded



Figure 4. Insertion Loss vs Frequency

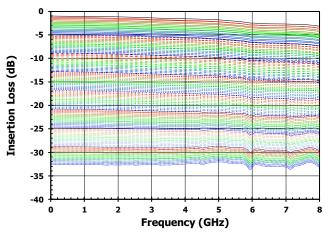


Figure 6. Input Return Loss vs Frequency
[All States]

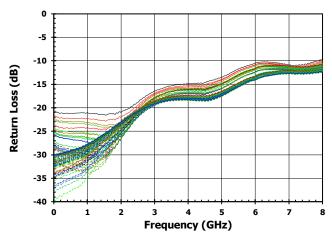


Figure 8. Output Return Loss vs Frequency
[All States]

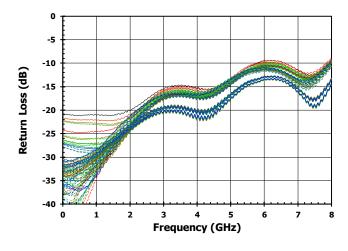


Figure 5. Insertion Loss vs Attenuator Setting

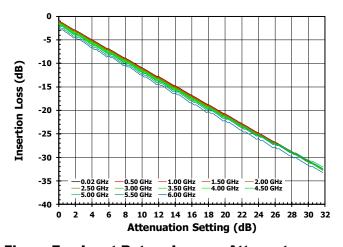


Figure 7. Input Return Loss vs Attenuator Setting

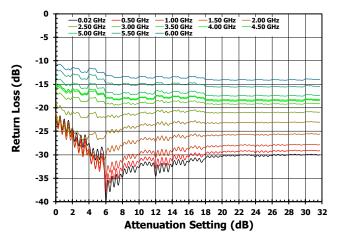


Figure 9. Output Return Loss vs Attenuator Setting

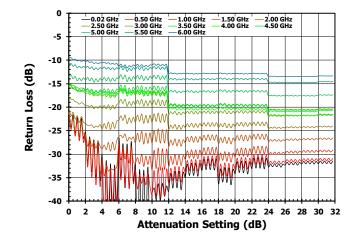




Figure 10. Worst Case Absolute Accuracy vs Frequency [LSB = 0.25dB]

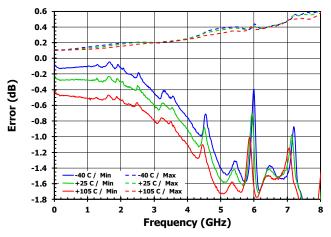


Figure 12. Worst Case Absolute Accuracy vs Frequency [LSB = 0.50dB]

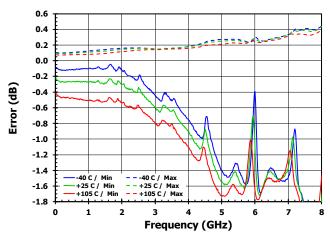


Figure 14. Worst Case Absolute Accuracy vs Frequency [LSB = 1.00dB]

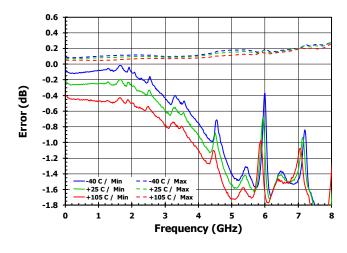


Figure 11. Absolute Accuracy vs Attenuator Setting [LSB = 0.25dB]

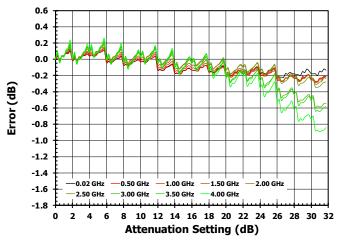


Figure 13. Absolute Accuracy vs Attenuator Setting [LSB = 0.50dB]

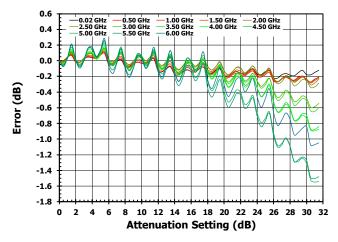


Figure 15. Absolute Accuracy vs Attenuator Setting [LSB = 1.00dB]

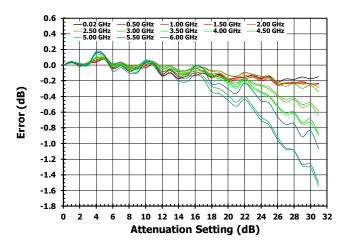




Figure 16. Worst Case Step Accuracy vs Frequency [LSB = 0.25dB]

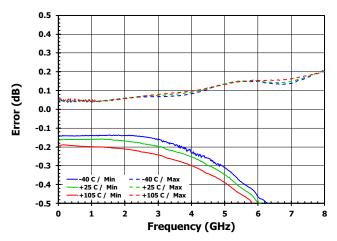


Figure 18. Worst Case Step Accuracy vs Frequency [LSB = 0.50dB]

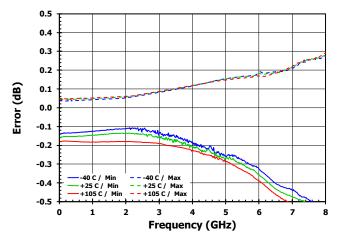


Figure 20. Worst Case Step Accuracy vs Frequency [LSB = 1.00dB]

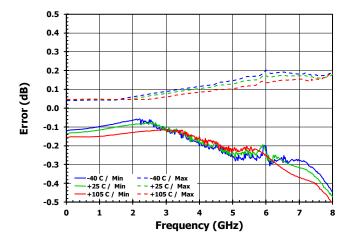


Figure 17. Step Accuracy vs Attenuator Setting [LSB = 0.25dB]

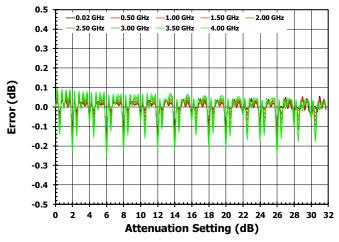


Figure 19. Step Accuracy vs Attenuator Setting [LSB = 0.50dB]

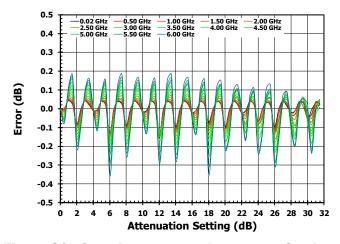


Figure 21. Step Accuracy vs Attenuator Setting [LSB = 1.00dB]

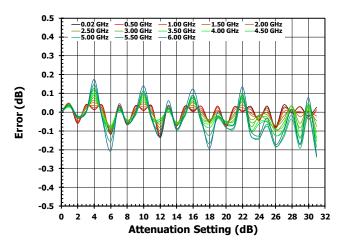




Figure 22. Relative Insertion Phase vs Frequency [All States]

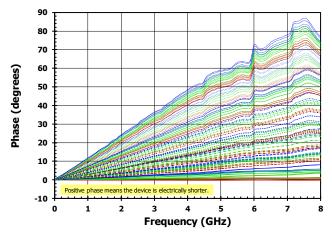


Figure 24. Attenuation vs Frequency [All States]

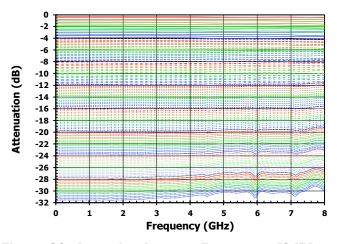


Figure 26. Insertion Loss vs Frequency [0dB]

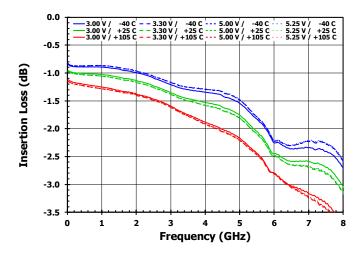


Figure 23. Relative Insertion Phase vs Attenuator Setting

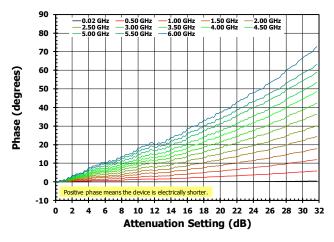


Figure 25. Attenuation vs Attenuator Setting

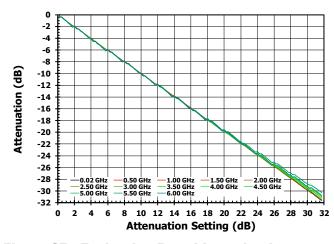


Figure 27. Evaluation Board Insertion Loss

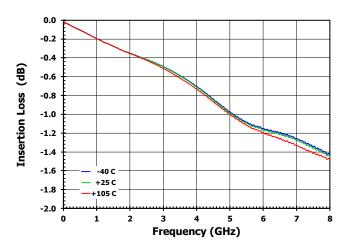




Figure 28. Input IP3 vs Frequency [0dB]

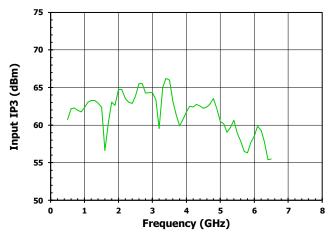


Figure 30. Compression vs Input Power [2GHz]

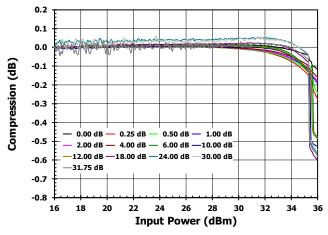


Figure 31. Typical Switching Time for a 0.25dB Attenuation Transition

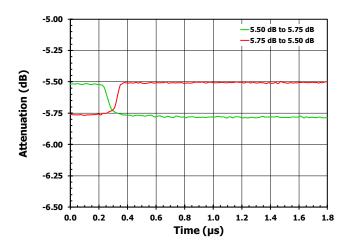


Figure 29. Input IP3 vs Attenuation [2GHz]

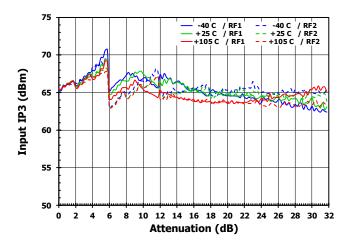
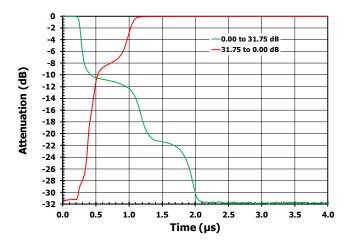


Figure 32. Switching Time between Maximum and Minimum Attenuation





Programming

The F1958 can be programmed using either the parallel or the serial mode, which is selectable via V_{MODE} (pin 3). The serial mode is selected by pulling V_{MODE} to a logic HIGH, and the parallel mode is selected by floating V_{MODE} or setting it to logic LOW.

Serial Mode

F1958 Serial Mode is selected by pulling V_{MODE} to a logic HIGH. The serial interface uses a 8-bit word with only 7 bits used. The serial word is shifted in LSB (D0) first. When serial programming is used, all the parallel control input pins (1, 19 - 24) must be grounded.

Table 8. 7-Bit SPI Word Sequence

Data Bit	Symbol
D7	Not Used
D6	Attenuation 16 dB Control Bit
D5	Attenuation 8 dB Control Bit
D4	Attenuation 4 dB Control Bit
D3	Attenuation 2 dB Control Bit
D2	Attenuation 1 dB Control Bit
D1	Attenuation 0.5 dB Control Bit
D0	Attenuation 0.25 dB Control Bit

Table 9. Truth Table for Serial Control Word

D7 (MSB)	D6	D5	D4	D3	D2	D1	D0 (LSB)	Attenuation (dB)
Х	0	0	0	0	0	0	0	0
Х	0	0	0	0	0	0	1	0.25
Х	0	0	0	0	0	1	0	0.5
Х	0	0	0	0	1	0	0	1
Х	0	0	0	1	0	0	0	2
Χ	0	0	1	0	0	0	0	4
Χ	0	1	0	0	0	0	0	8
Х	1	0	0	0	0	0	0	16
Х	1	1	1	1	1	1	1	31.75

In the Serial Mode, the F1958 is programmed via the serial port on the rising edge of Latch Enable (LE). It is required that LE be kept logic LOW until all data bits are clocked into the shift register. The F1958 will change attenuation state after the data word is latched into the active register. Refer to Figure 33.



Figure 33. Serial Register Timing Diagram

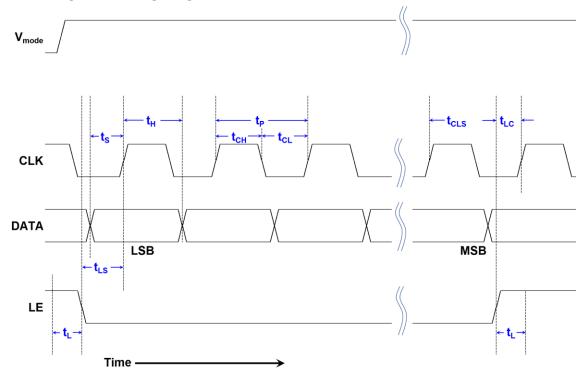


Table 10. SPI Timing Diagram Values for the Serial Mode

Parameter	Symbol	Test Condition	Min	Typical	Max	Units
CLK Frequency	f _C				25	MHz
CLK HIGH Duration Time	t _{CH}		20			ns
CLK LOW Duration Time	t _{CL}		20			ns
DATA to CLK Setup Time	t _S		10			ns
CLK Period [a]	t _P		40			ns
CLK to Data Hold Time	t _H		10			ns
Final CLK Rising Edge to LE Rising Edge	t _{CLS}		10			ns
LE to CLK Setup Time	t _{LS}		10			ns
LE Trigger Pulse Width	t∟		10			ns
LE Trigger to CLK Setup Time [b]	t _{LC}		10			ns

[[]a] $(t_{CH} + t_{CL}) \ge 1/\overline{f_C}$.

Serial Mode Default Startup Condition

When the device is first powered up, it will default to the maximum attenuation of 31.75dB independent of the V_{MODE} and parallel pin [D6:D0] conditions.

Table 11. Default Setting Truth Table for Serial Control Word

D7 (MSB)	D6	D5	D4	D3	D2	D1	D0 (LSB)	Attenuation (dB)
Х	1	1	1	1	1	1	1	31.75

15

[[]b] Once all desired data has been clocked in, LE must transition from LOW to HIGH after the minimum setup time t_{LC} and before any further CLK signals.



Parallel Control Mode

For the F1958, the user has the option of running in one of two parallel modes. Direct Parallel Mode or Latched Parallel Mode.

Direct Parallel Mode

Direct Parallel Mode is selected when V_{MODE} is floating or a logic LOW and LE is a logic HIGH. In this mode, the device will immediately react to any voltage changes on the parallel control pins (1, 19 - 24). Use Direct Parallel Mode for the fastest settling time. The serial pins, CLK and DATA, can be either grounded or left opened in the Parallel Mode.

Latched Parallel Mode

Latched Parallel Mode is selected when V_{MODE} is floating or a logic LOW and LE is toggled from logic LOW to HIGH. To utilize Latched Parallel Mode:

- Set V_{MODE} to logic LOW or leave floating.
- Set LE to logic LOW.
- Adjust pins (1, 19 24) to the desired attenuation setting. (Note the device will not react to these pins while LE is a logic LOW).
- Set LE to a logic HIGH. The device will then transition to the attenuation settings reflected by pins D6 D0.
- If LE is set to a logic LOW then the attenuator will not change state.

The truth table for the Parallel Mode is identical for bits D6 to D0 as shown in the Serial Mode truth table; see Table 9.

Figure 34. Latch Parallel Timing Diagram

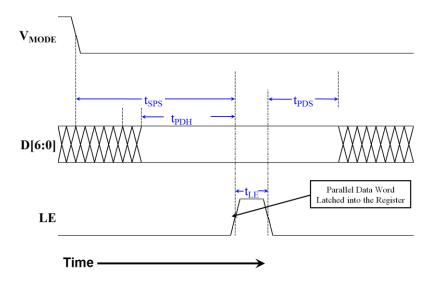


Table 12. Latched Parallel Timing Diagram Values

Parameter	Symbol	Min	Max	Units
Serial to Parallel Mode Setup Time	t _{SPS}	100		ns
Parallel Data Hold Time	t _{PDH}	10		ns
LE Minimum Pulse Width	t _{LE}	10		ns
Parallel Data Setup Time	t _{PDS}	10		ns



Evaluation Kit Picture

Figure 35. Top View

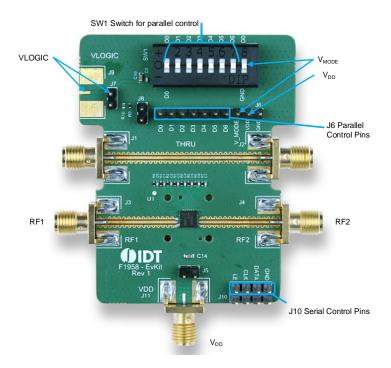
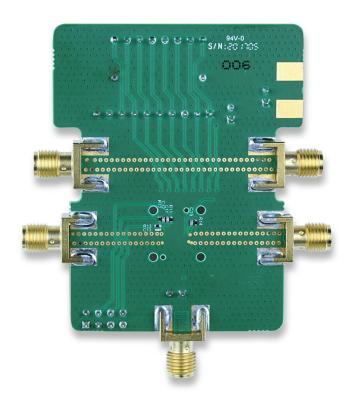


Figure 36. Bottom View





Evaluation Kit / Applications Circuit

Figure 37. Electrical Schematic

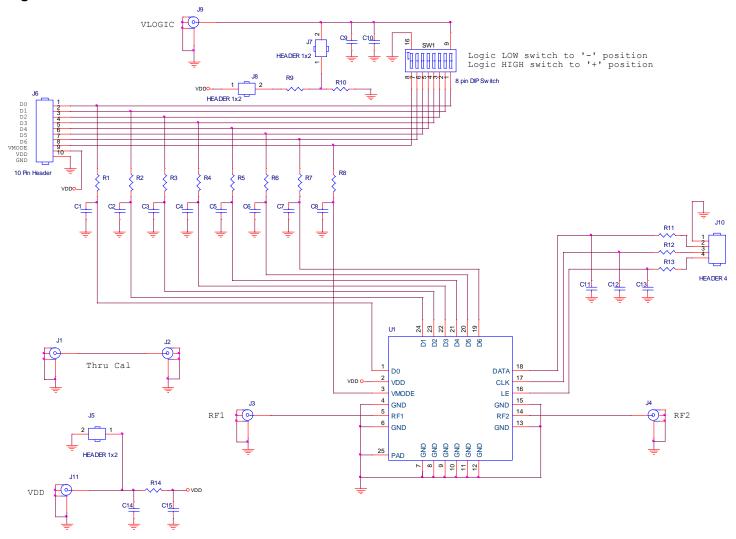




Table 13. Bill of Material (BOM)

Part Reference	QTY	Description	Manufacturer Part #	Manufacturer
C1 - C8, C11 - C13	11	100pF ±5%, 50V, C0G Ceramic Capacitor (0402)	GRM1555C1H101J	MURATA
C9, C15	2	1000pF ±5%, 50V, C0G Ceramic Capacitor (0402)	GRM1555C1H102J	MURATA
C10, C14	2	10nF ±5%, 50V, X7R Ceramic Capacitor (0603)	GRM188R71H103J	MURATA
R14	1	0Ω Resistors (0402)	ERJ-2GE0R00X	PANASONIC
R1 - R8, R11 - R13	11	100Ω ±1%, 1/10W, Resistor (0402)	ERJ-2RKF1000X	PANASONIC
R9	1	10kΩ ±1%, 1/10W, Resistor (0402)	ERJ-2RKF1002X	PANASONIC
J5, J7, J8	3	CONN HEADER VERT SGL 2 X 1 POS GOLD	961102-6404-AR	3M
J10	1	CONN HEADER VERT SGL 4 X 2 POS GOLD	67997-108HLF	Amphenol FCI
J6	1	CONN HEADER VERT SGL 10 X 1 POS GOLD	961110-6404-AR	3M
J1 - J4, J11	5	Edge Launch SMA (0.375 inch pitch ground, tab)	142-0701-851	Emerson Johnson
SW1	1	SWITCH 8 POSITION DIP SWITCH	KAT1108E	E-Switch
U1	1	DSA	F1958NBGK	IDT
	1	Printed Circuit Board	F1958 EVKit Rev 01	IDT
J9, R10		Do Not Populate (DNP)		



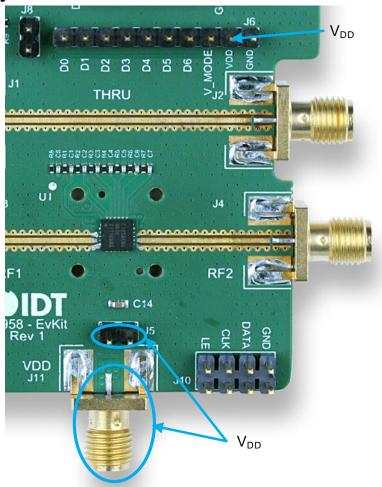
Evaluation Kit Operation

Power Supply Setup

Set up a power supply in the voltage range of 3.0V to 5.5V with the power supply output disabled. The voltage can be applied via one of the following connections (see Figure 38):

- J11 connector
- J5 header connection (note the polarity of the GND pin on this connector)
- Pin 9 (V_{DD}) and pin 10 (GND) on the J6 header connection

Figure 38. Power Supply Connections



Parallel Logic Control Setup

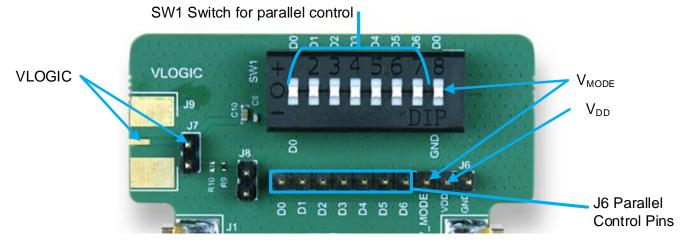
The Evaluation Board has the ability to control the F1958 in the Parallel Mode. For external control, apply logic voltages to the J6 header pins 1 through 7 (see Figure 39). For manual control, switches 1 through 7 on SW1 can be set. The switch is a three-position switch. The bottom position, "-" will ground the pin. The center position "O" will leave the pin open circuited. Setting the switch to the top position "+" will apply a voltage that is supplied to the switch.

The logic voltage can be applied in one of three ways:

- Apply a voltage through a SMA connector (J9). This connector is not supplied.
- Apply a voltage on pin 2 of the J7 header connector.
- Short out the two header connectors, J7 and J8, so a resistor divider will generate the correct logic voltage from the power supply on the Evaluation Board. The logic voltage will be V_{DD}.



Figure 39. Parallel Logic Voltage Connections

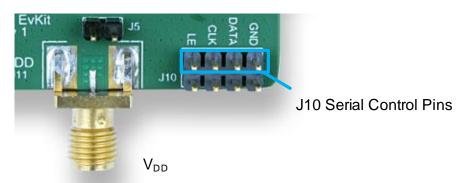


Serial Logic Control Setup

The Evaluation Board has the ability to control the F1958 in the Serial Mode. Connect the serial controller to the J10 header connection as shown in Figure 40. To use the Serial Mode, set SW1 switch 8 to the "+" or "O" position.

The attenuation setting can be programmed according to Table 9.

Figure 40. Serial Logic Connections



Power-On Procedure

Set up the voltage supplies and Evaluation Board as described in the "Power Supply Setup" section and either the "Parallel Logic Control Setup" or "Serial Logic Control Setup" sections above.

- Enable the power supply.
- Enable the proper attenuation setting according to Table 9.

Power-Off Procedure

- Set the logic control pins to a logic LOW.
- Disable the power supply.



Application Information

Digital Pin Voltage and Resistance Values

Table 14 provides the open-circuit DC voltage referenced to ground and resistance values for each of the control pins listed.

Table 14. Digital Pin Voltages and Resistance

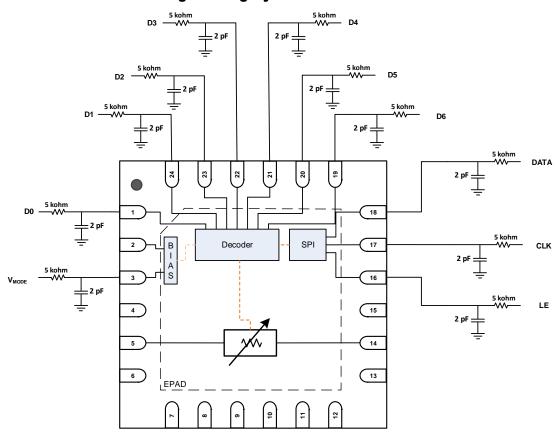
Pin	Name	Open Circuit DC Voltage	Internal Connection
3, 16, 17, 18	V _{MODE} , LE, CLK, DATA	0V	500kΩ pull-down resistor to GND
1, 19 - 24	D0, D6 – D1	0V	500kΩ pull-down resistor to GND

Power Supplies

A common power supply should be used for all pins requiring DC power. All supply pins should be bypassed with external capacitors to minimize noise and fast transients. Supply noise can degrade the noise figure and fast transients can trigger ESD clamps and cause them to fail. Supply voltage changes or transients should have a slew rate smaller than 1V/20µs. In addition, all control pins should remain at 0V (+/-0.3V) while the supply voltage ramps or while it returns to zero.

If control signal integrity is a concern and clean signals cannot be guaranteed due to overshoot, undershoot, ringing, etc., the following circuit at the input of each control pin is recommended. This applies to pins for the SPI (16, 17, 18), parallel (1, 19-24) and V_{MODE} pin (3) as shown below. Note the recommended resistor and capacitor values do not necessarily match the EVKit BOM for the case of poor control signal integrity. For multiple devices driven by a single control line, the component values will need to be adjusted accordingly so as not to load down the control line.

Figure 41. Control Pin Interface for Signal Integrity





Package Drawings

The package outline drawings are appended at the end of this document and are accessible from the link below. The package information is the most current data available.

www.idt.com/document/psc/nbnbg24-package-outline-40-x-40-mm-bodyepad-270mm-sq-050-mm-pitch-qfn

Ordering Information

Orderable Part Number	Package	MSL Rating	Shipping Packaging	Temperature
F1958NBGK	4mm x 4mm x 0.75mm 24 pin QFN	1	Tray	-40°C to +105°C
F1958NBGK8	4mm x 4mm x 0.75mm 24 pin QFN	1	Reel	-40°C to +105°C
F1958EVB	Evaluation Board			
F1958EVS	Evaluation Solution including the Evaluation Board, Controller Board, and cable. The Evaluation Software is available for download on the product page on the IDT website: http://www.idt.com/F1958			

Marking Diagram

F1958 NBGK Z1716AAG



- 1. Line 1 and 2 are the part number.
- 2. Line 3 "Z" is for die version.
- 3. Line 3 "yyww" = 1716 has two digits for the year and week that the part was assembled.
- 4. Line 3 "NG" denotes Assembly Lot number.

23



Revision History

Revision	Revision Date	Description of Change
0	March 26, 2018	Initial Release



Corporate Headquarters

6024 Silver Creek Valley Road San Jose, CA 95138 www.IDT.com

Sales

1-800-345-7015 or 408-284-8200 Fax: 408-284-2775 www.IDT.com/go/sales

Tech Support

www.IDT.com/go/support

DISCLAIMER Integrated Device Technology, Inc. (IDT) and its affiliated companies (herein referred to as "IDT") reserve the right to modify the products and/or specifications described herein at any time, without notice, at IDT's sole discretion. Performance specifications and operating parameters of the described products are determined in an independent state and are not guaranteed to perform the same way when installed in customer products. The information contained herein is provided without representation or warranty of any kind, whether express or implied, including, but not limited to, the suitability of IDT's products for any particular purpose, an implied warranty of merchantability, or non-infringement of the intellectual property rights of others. This document is presented only as a guide and does not convey any license under intellectual property rights of IDT or any third parties.

IDT's products are not intended for use in applications involving extreme environmental conditions or in life support systems or similar devices where the failure or malfunction of an IDT product can be reasonably expected to significantly affect the health or safety of users. Anyone using an IDT product in such a manner does so at their own risk, absent an express, written agreement by IDT.

Integrated Device Technology, IDT and the IDT logo are trademarks or registered trademarks of IDT and its subsidiaries in the United States and other countries. Other trademarks used herein are the property of IDT or their respective third party owners. For datasheet type definitions and a glossary of common terms, visit www.idt.com/go/glossary. All contents of this document are copyright of Integrated Device Technology, Inc. All rights reserved.